

Docket No.: 53074-025

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of : RESPONSE UNDER 37 C.F.R. 1.116
: EXPEDITED PROCEDURE
Tetsuzo UEDA :
Serial No.: 09/904,129 : Group Art Unit: 1765
Filed: July 11, 2001 : Examiner: Matthew J. Song
For: BUFFER LAYER AND GROWTH METHOD FOR SUBSEQUENT EPITAXIAL
GROWTH OF III-V NITRIDE SEMICONDUCTORS

AMENDMENT UNDER 37 C.F.R. 1.116

Commissioner for Patents
Washington, DC 20231

Sir:

In response to the final Office Action dated April 3, 2003, having a three-month shortened statutory period for response set to expire on July 3, 2003, reconsideration of the above-identified application is respectfully requested in view of the following amendment and remarks.

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